

# **STD2805**

## Low voltage fast-switching PNP power transistor

Preliminary Data

## **Features**

- Very low collector to emitter saturation voltage
- High current gain characteristic
- Fast-switching speed
- Surface-mounting DPAK (TO-252) power package in tape & reel (suffix "T4)
- Through-hole IPAK (TO-251) power package in tube (suffix "-1")

## Description

**Applications** 

Voltage regulators

CCFL drivers

Relay drivers

applications

The device is manufactured in PNP Planar technology by using a "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

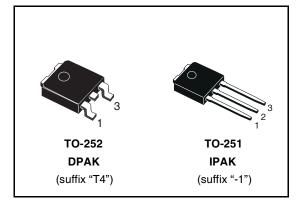
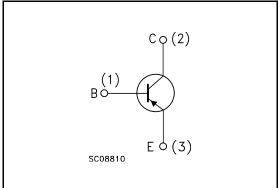


Figure 1. Internal schematic diagram



High efficiency low voltage switching

Table 1. Devices summary						
Order codes	Marking	Package	Packaging			
STD2805T4	D2805	DPAK	Tape & reel			
STD2805-1	D2805	IPAK	Tube			

June 2007

This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

# 1 Electrical ratings

Table 1.	Absolute maximum rating
	Absolute maximum ruting

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> =0)	-60	V
$V_{CEO}$	Collector-emitter voltage (I <sub>B</sub> =0)	-60	V
$V_{\text{EBO}}$	Emitter-base voltage (I <sub>C</sub> =0)	-6	V
۱ <sub>C</sub>	Collector current	-5	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	-10	А
Ι <sub>Β</sub>	Base current	-2	Α
P <sub>tot</sub>	Total dissipation at $T_c \le 25^{\circ}C$	15	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
Т <sub>Ј</sub>	Max. operating junction temperature	150	°C

#### Table 2. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	8.33	°C/W

# 2 Electrical characteristics

( $T_{case} = 25^{\circ}C$  unless otherwise specified)

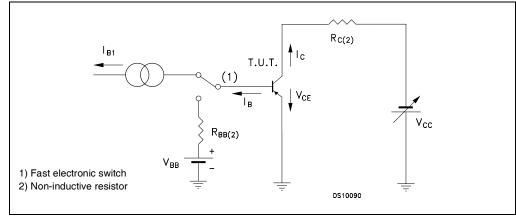
Table 5.	Electrical characterist	103					
Symbol	Parameter	Test Co	Min.	Тур.	Max.	Unit	
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> =0)	V <sub>CB</sub> = -60V				0.1	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> =0)	V <sub>EB</sub> = -5V				0.1	μA
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	I <sub>C</sub> =-100μΑ		-60			V
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage $(I_B = 0)$	I <sub>C</sub> =-1mA		-60			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> =-100μA		-6			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{C} = -100 \text{mA}$ $I_{C} = -2 \text{A}$ $I_{C} = -3 \text{A}$ $I_{C} = -5 \text{A}$	I <sub>B</sub> =-50mA I <sub>B</sub> =-150mA		-150 -200	-50 -300 -400 -600	mV mV mV mV
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	I <sub>C</sub> =-2A	I <sub>B</sub> =-50mA		-0.9	-1.2	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	I <sub>C</sub> =-100mA I <sub>C</sub> =-5A I <sub>C</sub> =-10A	V <sub>CE</sub> =-2V	200 85 20		400	
f <sub>T</sub>	Transition frequency	V <sub>CE</sub> =-10V	I <sub>C</sub> =-50mA		150		MHz
C <sub>CBO</sub>	Collector-base capacitance	V <sub>CB</sub> =-10V	f =1MHz		60		pF
t <sub>ON</sub> t <sub>s</sub> t <sub>f</sub>	Resistive load Turn-on time Storage time Fall time	V <sub>CC</sub> = -30V I <sub>B1</sub> =-I <sub>B2</sub> = -0	-		80 600 70		ns ns ns

Table 3. Electrical characteristics

Note (1) Pulsed duration = 300  $\mu s,$  duty cycle  ${\leq}1.5\%$ 



## 2.1 Test circuit



#### Figure 2. Resistive load switching test circuit



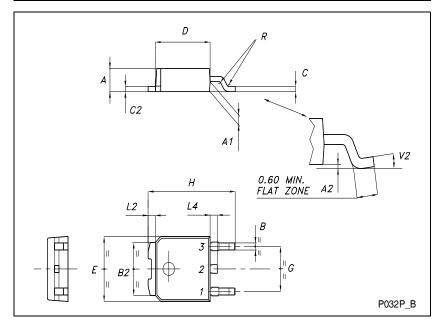
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



DIM.	mm			inch		
Divi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
С	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
Е	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
н	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0°		8°	0°		0°

## TO-252 (DPAK) MECHANICAL DATA

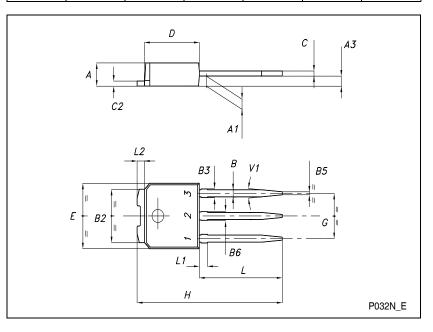




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DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	2.20		2.40	0.087		0.094	
A1	0.90		1.10	0.035		0.043	
A3	0.70		1.30	0.028		0.051	
В	0.64		0.90	0.025		0.035	
B2	5.20		5.40	0.204		0.213	
B3			0.85			0.033	
B5		0.30			0.012		
B6			0.95			0.037	
С	0.45		0.60	0.018		0.024	
C2	0.48		0.60	0.019		0.024	
D	6.00		6.20	0.237		0.244	
Е	6.40		6.60	0.252		0.260	
G	4.40		4.60	0.173		0.181	
Н	15.90		16.30	0.626		0.642	
L	9.00		9.40	0.354		0.370	
L1	0.80		1.20	0.031		0.047	
L2		0.80	1.00		0.031	0.039	
V1		10°			10°		





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# 4 Revision history

## Table 4. Revision history

Date	Revision	Changes	
26-Jun-2007	1	Initial release.	



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